



# 650-670W

G8P66B-G | 132-cell

Bifacial Dual Glass

12BB Half-cut Mono Perc



## KEY FEATURES



### 12BB Cell

New circuit design, lower internal current, lower Rs loss Ga dopped wafer, attenuation < 2% (1st year) / ≤0.45% (Linear)



### Lower LCOE

2% more power generation, lower LCOE



### IP68 Junction Box

High waterproof level



### Significantly Lower the Risk of Hot Spot

Special circuit design with much lower hot spot temperature



### Excellent Anti-PID Performance

2 times of industry standard Anti-PID test



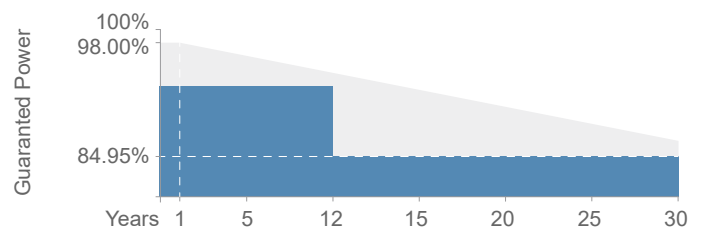
## INTRODUCTION

### SYSTEM & PRODUCT CERTIFICATES

- IEC 61215 / IEC 61730 / UL 61730
- ISO 9001: 2015 Quality Management System
- ISO 14001: 2015 Environment Management System
- ISO 45001: 2018 Occupational Health and Safety Management Systems

### PERFORMANCE WARRANTY

12 Years Product Warranty    30 Years Linear Power Warranty



**670W**

Output

**21.60%**

Efficiency

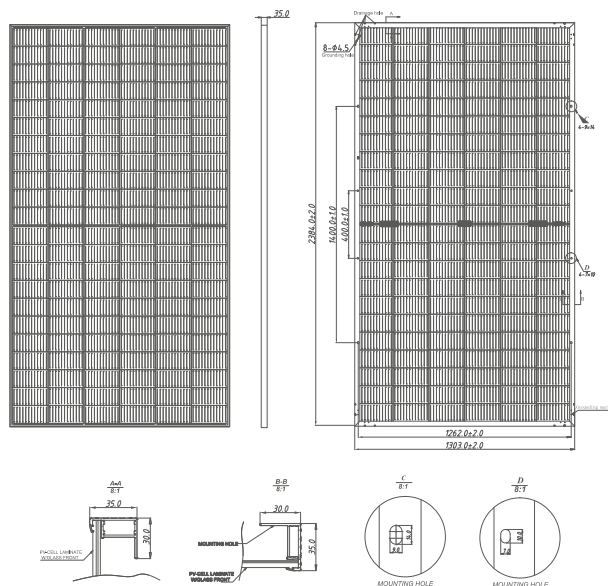
**≤2%**

First Year Degradation

**≤0.45%**

Year 2-30 Power Degradation

**TECHNICAL DRAWING**



**Mechanical Characteristics**

Cell Type	P-Type Perc 210 Cell (12 BusBar)
Number of Cells	132(6×22)
Dimensions	2384×1303×35mm
Weight	38.5kg
Front Glass	2.0mm AR Coating Semi-tempered Glass
Back Glass	2.0mm Glazed Semi-tempered Glass
Frame	Anodized Aluminum Alloy
Output Cables	4mm <sup>2</sup> (IEC), 12AWG(UL) 300mm in Length or Customized Length
Junction Box	IP68, 3 Bypass Diodes
Connector	T01/LJQ-3-CSY/MC4/MC4-EVO2
Packaging	31 Pieces/Pallet, 558/465(USA) Pieces/40' container

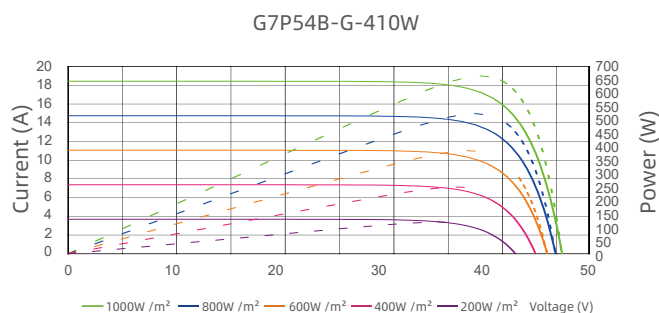
**Electrical Characteristics (STC: AM1.5 1000W/m<sup>2</sup> 25°C NOCT: AM1.5 800W/m<sup>2</sup> 20°C 1m/s)**

Model	G8P66B-G-650W		G8P66B-G-655W		G8P66B-G-660W		G8P66B-G-665W		G8P66B-G-670W	
	STC	NOCT	STC	NOCT	STC	NOCT	STC	NOCT	STC	NOCT
Maximum Power (Pmax/W)	650	492	655	495	660	499	665	503	670	507
Operating Voltage (Vmpp/V)	37.80	35.40	38.00	35.60	38.20	35.80	38.40	36.00	38.60	36.10
Operating Current (Impp/A)	17.20	13.88	17.24	13.91	17.28	13.95	17.32	13.99	17.36	14.02
Open-circuit Voltage (Voc/V)	45.40	42.90	45.60	43.10	45.80	43.30	46.00	43.50	46.20	43.70
Short-circuit Current (Isc/A)	18.29	14.74	18.33	14.77	18.37	14.81	18.41	14.84	18.45	14.87
Modules Efficiency (%)	20.90		21.10		21.30		21.40		21.60	

**Bifacial Output-Rearside Power Gain (440W)**

Power Gain	5%	10%	15%	20%	25%
Maximum Power (Pmax)[W]	688	721	753	786	819
Open-Circuit Voltage (Voc)[V]	45.40	45.40	45.40	45.40	45.40
Maximum Power Voltage (Vmp) [V]	38.00	38.00	38.00	38.00	38.00
Short-Circuit Current (Isc)[A]	19.22	20.13	21.05	21.96	22.88
Maximum Power Current (Imp) [A]	18.10	18.96	19.83	20.69	21.55

**I-V Characteristics**



**Operating Conditions**

Maximum System Voltage	1500V/DC
Operating Temperature	-40°C~+85°C
Maximum Series Fuse Rating	35A
Mechanical Load Front Rear	5400Pa
Mechanical Load Back Rear	2400Pa
Nominal operating cell temperature	43±2°C
Bifaciality	70±5%

